

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> ( Not for submission under 37 CFR 1.99)		Application Number	10551923
		Filing Date	2005-10-03
		First Named Inventor	Tomohiro Kawase
		Art Unit	<del>1722</del> 1792
		Examiner Name	F. C. Hiteshew
		Attorney Docket Number	20239/0202145-US0

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/F.H./	1	YOSHIHIRO HOSOKAWA, et al., Development of 3-Inch-Diameter InP Single Crystals with Low Dislocation Density Using the VCZ Method, Sumitomo Electric Technical Review, No. 35, January 1993, pp. 69-73	<input type="checkbox"/>
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